

**Type 2N3634**  
**Geometry TBD**  
**Polarity PNP**  
**Qual Level: Pending**

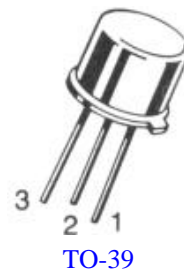
**Generic Part Number:**  
**2N3634**

**REF: MIL-PRF-19500/357**

**Features:**

[Request Quotation](#)

- General-purpose low-power amplifier transistor which operates over a wide temperature range.
- Housed in a [TO-39](#) case.
- Also will be available in chip form using the TBD chip geometry.
- The Min and Max limits shown are per [MIL-PRF-19500/357](#) which Semicoa meets in all cases.



**Maximum Ratings**

$T_C = 25^{\circ}\text{C}$  unless otherwise specified

Rating	Symbol	Rating	Unit
Collector-Emitter Voltage	$V_{CEO}$	140	V
Collector-Base Voltage	$V_{CBO}$	140	V
Emitter-Base Voltage	$V_{EBO}$	5.0	V
Collector Current, Continuous	$I_C$	1.0	A
Operating Junction Temperature	$T_J$	-65 to +200	$^{\circ}\text{C}$
Storage Temperature	$T_{STG}$	-65 to +200	$^{\circ}\text{C}$

## Electrical Characteristics

$T_C = 25^\circ\text{C}$  unless otherwise specified

OFF Characteristics	Symbol	Min	Max	Unit
Collector-Base Breakdown Voltage $I_C = 10 \mu\text{A}$	$V_{(BR)CBO}$	140	---	V
Collector-Emitter Breakdown Voltage $I_C = 10 \text{mA}$	$V_{(BR)CEO}$	140	---	V
Emitter-Base Breakdown Voltage $I_E = 10 \mu\text{A}$ , pulsed	$V_{(BR)EBO}$	5.0	---	V
Collector-Base Cutoff Current $V_{CB} = 100 \text{V}$	$I_{CBO1}$	---	100	nA
$V_{CB} = -100 \text{V}$ , $T_A = +150^\circ\text{C}$	$I_{CBO2}$	---	100	$\mu\text{A}$
Emitter-Base Cutoff Current $V_{EB} = 3.0 \text{V}$	$I_{EBO}$	---	50	nA
Collector-Emitter Cutoff Current $V_{CE} = 100 \text{V}$	$I_{CEO}$	---	10	$\mu\text{A}$

ON Characteristics	Symbol	Min	Max	Unit
<b>Forward current Transfer Ratio</b>				
$I_C = 0.1 \text{mA}$ , $V_{CE} = 10 \text{V}$ (pulsed)	$h_{FE1}$	25	---	---
$I_C = 1.0 \text{mA}$ , $V_{CE} = 1.0 \text{V}$ (pulsed)	$h_{FE2}$	45	---	---
$I_C = 10 \text{mA}$ , $V_{CE} = 10 \text{V}$ (pulsed)	$h_{FE3}$	50	---	---
$I_C = 50 \text{mA}$ , $V_{CE} = 10 \text{V}$ (pulsed)	$h_{FE4}$	50	150	---
$I_C = 150 \text{mA}$ , $V_{CE} = 10 \text{V}$ (pulsed)	$h_{FE5}$	30	---	---
$I_C = 50 \text{mA}$ , $V_{CE} = 10 \text{V}$ (pulsed), $T_A = -55^\circ\text{C}$	$h_{FE6}$	25	---	---
<b>Collector-Emitter Saturation Voltage</b>				
$I_C = 10 \text{mA}$ , $I_B = 1 \text{mA}$ (pulse test)	$V_{CE(sat)1}$	---	0.3	V dc
$I_C = 50 \text{mA}$ , $I_B = 5 \text{mA}$ (pulse test)	$V_{CE(sat)2}$	---	0.6	V dc
<b>Base-Emitter Saturation Voltage</b>				
$I_C = 10 \text{mA}$ , $I_B = 1.0 \text{mA}$ (pulse test)	$V_{BE(sat)1}$	---	0.8	V dc
$I_C = 50 \text{mA}$ , $I_B = 5 \text{mA}$ (pulse test)	$V_{BE(sat)2}$	0.65	0.9	V dc

Switching Characteristics	Symbol	Min	Max	Unit
<b>Pulse Delay Time</b>				
Per Figure 3 of MIL-S-19500/357	$t_d$	---	100	ns
<b>Pulse Rise Time</b>				
$I_C = 500 \text{mA}$ , $I_{B1} = 50 \text{mA}$ , $V_{EB} = 2 \text{V}$	$t_r$	---	100	ns
<b>Pulse Storage Time</b>				
$I_C = 500 \text{mA}$ , $I_{B1} = I_{B2} = 50 \text{mA}$	$t_s$	---	500	ns
<b>Pulse Fall Time</b>				
$I_C = 500 \text{mA}$ , $I_{B1} = I_{B2} = 50 \text{mA}$	$t_f$	---	150	ns
<b>t off</b>				
$I_C = 500 \text{mA}$ , $I_{B1} = I_{B2} = 50 \text{mA}$	$t_{off}$	---	600	ns

Small Signal Characteristics	Symbol	Min	Max	Unit
Short Circuit Forward Current Transfer Ratio $V_{CE} = 30\text{ V}, I_C = 30\text{ mA}, f = 100\text{ MHz}$	$ h_{FE} $	1.5	8.0	---
Short Circuit Forward Current Transfer Ratio $V_{CE} = 10\text{ V}, I_C = 10\text{ mA}, f = 1\text{ kHz}$	$h_{FE}$	40	160	---
Short-Circuit Input Impedance $V_{CE} = 10\text{ V}, I_C = 10\text{ mA}, f = 1\text{ kHz}$	$h_{IE}$	100	600	ohms
Open-Circuit, Reverse Voltage Transfer Ratio $V_{CE} = 10\text{ V}, I_C = 10\text{ mA}, f = 1\text{ kHz}$	$h_{RE}$	---	$3 \times 10^{-4}$	---
Open Circuit Output Admittance $V_{CE} = 10\text{ V}, I_C = 10\text{ mA}, f = 1\text{ kHz}$	hoe	---	200	$\mu\text{S}$
Open Circuit Output Capacitance $V_{CB} = 20\text{ V}, I_E = 0, 100\text{ kHz} < f < 1\text{ MHz}$	$C_{OBO}$	---	10	pF
Input Capacitance, Output Open Circuited $V_{EB} = 1\text{ V}, I_C = 0, 100\text{ kHz} < f < 1\text{ MHz}$	$C_{IBO}$	---	75	pF
Noise Figure $V_{CE} = 10\text{ V}, I_C = 0.5\text{ mA}, R_g = 1\text{ kohm}$				
$f = 100\text{ Hz}$	NF	---	5	dB
$f = 1\text{ kHz}$	NF	---	3	dB
$f = 10\text{ kHz}$	NF	---	3	dB